



ES2A THRU ES2J

2.0 AMPS. Super Fast Surface Mount Rectifiers



Voltage Range
50 to 600 Volts
Current
2.0 Amperes

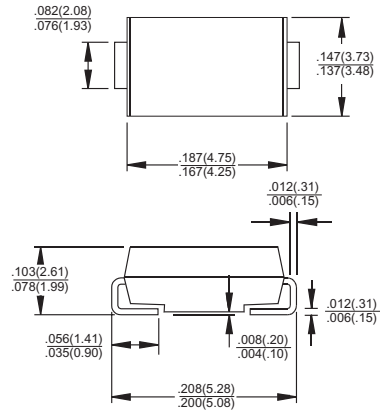
Features

- ✦ Glass passivated junction chip
- ✦ For surface mounted application
- ✦ Low profile package
- ✦ Built-in strain relief
- ✦ Ideal for automated placement
- ✦ Easy pick and place
- ✦ Superfast recovery time for high efficiency
- ✦ Glass passivated chip junction
- ✦ High temperature soldering:
260°C/10 seconds at terminals
- ✦ Plastic material used carries Underwriters
Laboratory Classification 94V-O

Mechanical Data

- ✦ Cases: Molded plastic
- ✦ Terminals: Solder plated
- ✦ Polarity: Indicated by cathode band
- ✦ Packing: 12mm tape per E1A STD RS-481
- ✦ Weight: 0.093 gram

SMB/DO-214AA



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	ES 2A	ES 2B	ES 2C	ES 2D	ES 2F	ES 2G	ES 2H	ES 2J	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current See Fig. 1	$I_{(AV)}$	2.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	50								A
Maximum Instantaneous Forward Voltage @ 2.0A	V_F	0.95			1.3		1.7			V
Maximum DC Reverse Current @ $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A=100^\circ\text{C}$	I_R					10				uA
						350				uA
Maximum Reverse Recovery Time (Note 1)	T_{rr}	35								nS
Typical Junction Capacitance (Note 2)	C_j	25				20				pF
Maximum Thermal Resistance (Note 3)	$R_{\theta JA}$ $R_{\theta JL}$					75				°C/W
						20				
Operating Temperature Range	T_J	-55 to +150								°C
Storage Temperature Range	T_{STG}	-55 to +150								°C

Notes: 1. Reverse Recovery Test Conditions: $I_F=0.5A$, $I_R=1.0A$, $IRR=0.25A$

2. Measured at 1 MHz and Applied $V_R=4.0$ Volts

3. Units Mounted on P.C.B. 0.4 x 0.4" (10 x 10mm) Pad Areas

RATINGS AND CHARACTERISTIC CURVES (ES2A THRU ES2J)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

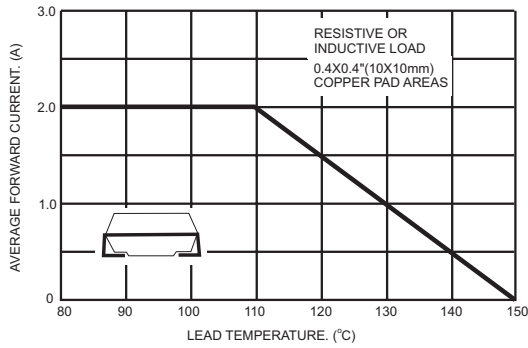


FIG.2- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

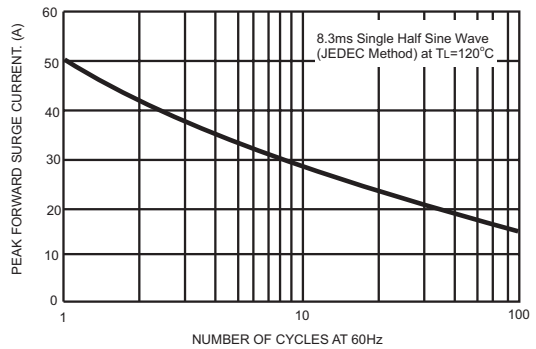


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

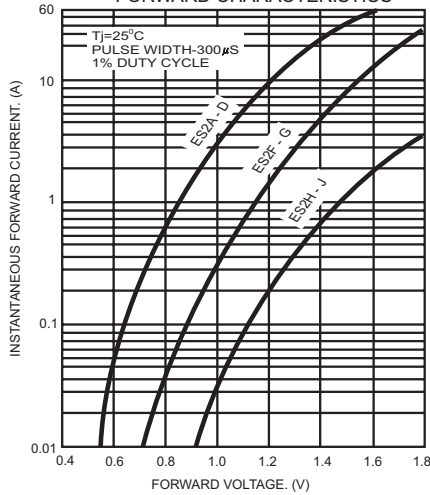


FIG.4- TYPICAL REVERSE CHARACTERISTICS

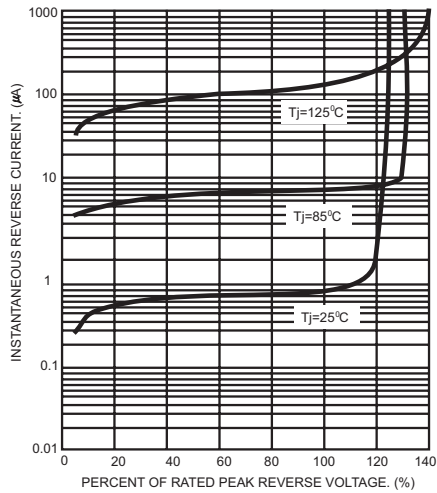


FIG.5- TYPICAL JUNCTION CAPACITANCE

